

# Migration from Micron® MT29F (1-2-4 Gb) to SkyHigh S34ML-1 (1-2-4 Gb)

AN200963 details how to migrate designs from Micron MT29F NAND flash memory devices to SkyHigh S34ML-1 NAND flash memory devices.

## 1 Introduction

This application note details how to migrate designs from Micron 1-Gb MT29F1G08, 2-Gb MT29F2G08, and 4-Gb MT29F4G08 NAND flash memory devices to SkyHigh's 1-Gb S34ML01G1, 2-Gb S34ML02G1, and 4-Gb S34ML04G1 NAND flash memory devices, respectively. S34ML01G1/ S34ML02G1/ S34ML04G1 devices are 3.0-volt NAND flash memory manufactured with the 4x nm technology.

**Note:** All the information provided in this guide illustrates only the differences for each section. See the respective data sheets for more information.

SkyHigh S34ML-1 NAND flash family devices are compatible with the Micron MT29F NAND flash family devices with respect to:

- Block, page, byte size architecture
- JEDEC standard-compliant software command set

## 2 Feature Comparison

Most of the features of S34ML-1 and MT29F are similar, except for a few differences that are highlighted in [Table 1](#). See the respective Micron MT29F and SkyHigh S34ML-1 data sheets to verify any other features.

Table 1. Feature Comparison

	SkyHigh S34ML-1	Micron MT29F
Generic Part#	S34ML-1	MT29F
V <sub>CC</sub>	3 V (2.7-3.6 V)	3 V and 1.8 V (2.7-3.6/1.7-1.95 V)
I/O Bus width	x8/x16	x8/x16
Sequential access time (Page Read (ns))	25	20
Block Erase time (ms)	2	700 μs
ECC Capability	1-bit/512 + 16-byte ECC	4-bit/516 + 8-byte ECC

### 3 AC Specification

The S34ML-1 and MT29F have primarily compatible specifications. Differences in AC characteristics between the devices are highlighted in [Table 2](#). The potential impact of any parameter specification differences should be evaluated and validated. See the respective Micron MT29F and SkyHigh S34ML-1 data sheets to verify the most up-to-date specifications.

Table 2. AC Characteristics

Parameter	Symbol	SkyHigh S34ML-1			Micron MT29F		
		Min	Max	Unit	Min	Max	Unit
ALE setup time	$t_{ALS}$	12	—	ns	10	—	ns
CLE setup time	$t_{CLS}$	12	—	ns	10	—	ns
CE# setup time	$t_{CS}$	20	—	ns	15	—	ns
Data setup time	$t_{DS}$	12	—	ns	7	—	ns
Read cycle time	$t_{RC}$	25	—	ns	20	—	ns
RE# HIGH hold time	$t_{REH}$	10	—	ns	7	—	ns
RE# pulse width	$t_{RP}$	12	—	ns	10	—	ns
Write cycle time	$t_{WC}$	25	—	ns	20	—	ns
WE# HIGH hold time	$t_{WH}$	10	—	ns	7	—	ns
WE# pulse width	$t_{WP}$	12	—	ns	10	—	ns
CE# HIGH to output HI-Z	$t_{CHZ}$	—	30	ns	—	50	ns
RE# access time	$t_{REA}$	—	20	ns	—	16	ns

Table 3. AC Test Conditions

Parameter	SkyHigh S34ML-1	Micron MT29F
Output load (2.7 V-3.6 V) 1 TTL Gate and CL	50 pF	30 pF

### 4 DC Specification

The S34ML-1 and MT29F have primarily compatible specifications. Differences in DC characteristics between the devices are highlighted in [Table 4](#). The potential impact of any parameter specification differences should be evaluated and validated. See the respective Micron MT29F and SkyHigh S34ML-1 data sheets to verify the most up-to-date specifications.

Table 4. DC Characteristics

Parameter	Symbol	SkyHigh S34ML-1				Micron MT29F			
		Min	Typ	Max	Units	Min	Typ	Max	Units
Sequential READ current	$I_{CC1}$	—	15	30	mA	—	25	35	mA
Program current	$I_{CC2}$	—	15	30	mA	—	25	35	mA
Erase current	$I_{CC3}$	—	15	30	mA	—	25	35	mA

## 5 Device ID

This section provides a comparison between Micron and SkyHigh flash memory Device IDs.

Table 5. Manufacture/Device ID

SkyHigh S34ML-1				Micron MT29F			
Manufacture ID	Device ID			Manufacture ID	Device ID		
	1G	2G	4G		1G	2G	4G
01h	F1h	DAh	DCh	2Ch	20h	AAh/BAh/ CAh/DAh	DCh/CCh/ ACh/BCh/ A3h/B3h/ D3h/C3h

## 6 References

- [SkyHigh NAND S34ML Flash Memory Family Data Sheet, Publication Number S34ML01G1\\_4G1](#)
- Micron MT29F Data Sheet

## Document History Page

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Rev.	ECN No.	Orig. of Change	Submission Date	Description of Change
**	–	–	07/20/2012	Initial version
*A	4940076	YOQI	09/29/2015	Updated in Cypress template
*B	5807219	AESATMP8	07/10/2017	Updated logo and Copyright.
*C	6272156	MNAD	08/03/2018	Updated template
*D		MNAD	06/04/2019	Updated to SkyHigh format